

	<p>SI7682DP-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI7682DP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 20A PPAK SO-8</p> <p>Datenblätter:  SI7682DP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 13087 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7682DP-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 20A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	13087 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	5W (Ta), 27.5W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	20A (Tc)
Rds On (Max) @ Id, Vgs	9 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	38nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1595pF @ 15V
Verpackung	Tape & Reel (TR)












SI7682DP-T1-GE3 ist neu im Original, Suche SI7682DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7682DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7682DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7682DP-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 20A PPAK SO-8</p>	 <p>SI7674DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SI7674DP-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SI7684DP-T1-E3 VISHAY VISHAY QFN8</p>
 <p>SI7686 SI SI7686 SI</p>	 <p>SI7684DP-T1-GE3 Vishay Precision Group SI7684DP-T1-GE3 VISHAY</p>	 <p>SI7682DY-T1-GE3 VISHAY SI7682DY-T1-GE3 VISHAY</p>	 <p>SI7682DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 20A PPAK SO-8</p>

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|--|--|--|---|--|
|  SI7655DN-T1-GE3 |  SI7655DN-T1-GE3 |  SI7658ADP |  SI7658ADP-T1-E3 |  SI7658ADP-T1-GE3 |
|  SI7658ADP-T1-GE3 |  SI7658DP-T1-GE3 |  SI7660CJ |  SI7660DY |  SI7660DY-T1 |
|  SI7660DY-T1-E3 |  SI7661CJ |  SI7661CSA |  SI7661CSA+ |  SI7668ADP-T1-E3 |
|  SI7668ADP-T1-E3 |  SI7668ADP-T1-GE3 |  SI7668ADP-T1-GE3 |  SI7674DP |  SI7674DP-T1-GE3 |
|  SI7674DP-T1-GE3 |  SI7682DP |  SI7682DP-T1-E3 |  SI7682DP-T1-E3 |  SI7682DP-T1-GE3 |
|  SI7682DY-T1-GE3 |  SI7684DP-T1-GE3 |  SI7686DP |  SI7686DP-T1 |  SI7686DP-T1-E3 |
|  SI7686DP-T1-E3 |  SI7686DP-T1-GE3 |  SI7686DP-T1-GE3 |  SI7703DN |  SI7703EDN |
|  SI7703EDN-T1 |  SI7703EDN-T1-E3 |  SI7703EDN-T1-E3 |  SI7703EDN-T1-GE3 |  SI7703EDN-T1-GE3 |
|  SI7703EDN-T1-E3 |  SI7705DN |  SI7705DN-T1 |  SI7705DN-T1-E3 |  SI7716ADN |
|  SI7716ADN-T1-E3 |  SI7716ADN-T1-GE3 |  SI7716ADN-T1-GE3 |  SI7716ADN-T1-GE3 |  SI7716DN-T1-GE3 |

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